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Texas Instruments CSD13381F4

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Product

Texas **INSTRUMENTS** 

CSD13381F4

SLPS448D-JULY 2013-REVISED MAY 2015

## CSD13381F4 12 V N-Channel FemtoFET™ MOSFET

#### 1 Features

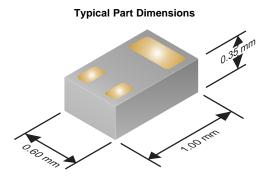
- Low On-Resistance
- Low Q<sub>a</sub> and Q<sub>ad</sub>
- Low Threshold Voltage
- Ultra-Small Footprint (0402 Case Size) – 1.0 mm × 0.6 mm
- Ultra-Low Profile
  - 0.35 mm Height
- Integrated ESD Protection Diode
  - Rated >4 kV HBM
  - Rated >2 kV CDM
- Lead and Halogen Free
- **RoHS** Compliant

### 2 Applications

- Optimized for Load Switch Applications
- Optimized for General Purpose Switching Applications
- Single-Cell Battery Applications
- Handheld and Mobile Applications

#### Description 3

This 140 mΩ, 12 V N-channel FemtoFET™ MOSFET technology is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing at least a 60% reduction in footprint size.



### **Product Summary**

Support & Community

T <sub>A</sub> = 25°	T <sub>A</sub> = 25°C TYPICAL VA			
V <sub>DS</sub>	Drain-to-Source Voltage	12		V
Qg	Gate Charge Total (4.5 V)	1060		рС
Q <sub>gd</sub>	Gate Charge Gate-to-Drain	140		рС
		$V_{GS} = 1.8 V$	310	mΩ
R <sub>DS(on)</sub>	Drain-to-Source On-Resistance	V <sub>GS</sub> = 2.5 V	170	mΩ
		V <sub>GS</sub> = 4.5 V	140	mΩ
V <sub>GS(th)</sub>	Threshold Voltage	0.85		V

### Ordering Information<sup>(1)</sup>

<u>_</u>									
Device	Qty	Media	Package	Ship					
CSD13381F4	3000	7-Inch	Femto (0402) 1.0 mm x	Tape and					
CSD13381F4T	250	Reel	0.6 mm SMD Lead Less	Reel					

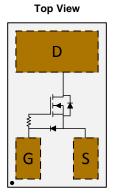
(1) For all available packages, see the orderable addendum at the end of the data sheet.

### **Absolute Maximum Ratings**

T <sub>A</sub> = 25	°C unless otherwise stated	VALUE	UNIT	
$V_{\rm DS}$	Drain-to-Source Voltage	12	V	
V <sub>GS</sub>	Gate-to-Source Voltage	8	V	
ID	Continuous Drain Current, $T_A = 25^{\circ}C^{(1)}$	2.1	А	
I <sub>DM</sub>	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	7	А	
	Continuous Gate Clamp Current	35	mA	
I <sub>G</sub>	Pulsed Gate Clamp Current <sup>(2)</sup>	350	ША	
PD	Power Dissipation <sup>(1)</sup>	500	mW	
ESD	Human Body Model (HBM)	4	kV	
Rating	Charged Device Model (CDM)	2	kV	
T <sub>J</sub> , T <sub>stg</sub>	Operating Junction and Storage Temperature Range	–55 to 150	°C	
E <sub>AS</sub>	Avalanche Energy, single pulse I_D = 7.4 A, L = 0.1 mH, R_G = 25 $\Omega$	2.7	mJ	

(1) Typical  $R_{\theta JA}$  = 90°C/W on 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu pad on a 0.06 inch (1.52 mm) thick FR4 PCB.

(2) Pulse duration ≤300 µs, duty cycle ≤2%







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### **4** Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	nanges from Revision C (September 2014) to Revision D Page
•	Corrected typo for I <sub>GSS</sub> Test Condition
C	nanges from Revision B (February 2014) to Revision C Page
•	Corrected timing V <sub>DS</sub> to read 6 V
С	nanges from Revision A (November 2013) to Revision B Page
•	Added I <sub>G</sub> parameter
•	Lowered I <sub>DSS</sub> limit
•	Lowered I <sub>GSS</sub> limit
С	nanges from Original (July 2013) to Revision A Page
•	Updated device ordering information1
•	Changed test voltage conditions 3
•	Changed Figure 4 Gate Charge graph 5



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### **5** Specifications

### 5.1 Electrical Characteristics

#### $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV <sub>DSS</sub>	Drain-to-Source Voltage	V <sub>GS</sub> = 0 V, I <sub>DS</sub> = 250 μA	12			V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 9.6 V			100	nA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = 8 V			50	nA
V <sub>GS(th)</sub>	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}$ , $I_{DS} = 250 \ \mu A$	0.65	0.85	1.10	V
		V <sub>GS</sub> = 1.8 V, I <sub>DS</sub> =0.5 A		310	400	mΩ
R <sub>DS(on)</sub>	Drain-to-Source On-Resistance	V <sub>GS</sub> = 2.5 V, I <sub>DS</sub> =0.5 A		170	225	mΩ
. ,	On Resistance	V <sub>GS</sub> = 4.5 V, I <sub>DS</sub> = 0.5 A		140	180	mΩ
9 <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 6 V, I <sub>DS</sub> = 0.5 A		3.2		S
DYNAMI	C CHARACTERISTICS					
Ciss	Input Capacitance			155	200	pF
Coss	Output Capacitance	$V_{GS} = 0 V, V_{DS} = 6 V,$ f = 1 MHz		47	62	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	$\int = 1 \text{ IVI IZ}$		2.5	3.3	pF
R <sub>G</sub>	Series Gate Resistance			23		Ω
Q <sub>g</sub>	Gate Charge Total (4.5 V)			1060	1400	рС
Q <sub>gd</sub>	Gate Charge Gate-to-Drain			140		рС
Q <sub>gs</sub>	Gate Charge Gate-to-Source	$V_{DS} = 6 \text{ V}, \text{ I}_{DS} = 0.5 \text{ A}$		230		рС
Q <sub>g(th)</sub>	Gate Charge at V <sub>th</sub>			155		рС
Q <sub>oss</sub>	Output Charge	V <sub>DS</sub> = 6 V, V <sub>GS</sub> = 0 V		1120		рС
t <sub>d(on)</sub>	Turn On Delay Time			3.7		ns
t <sub>r</sub>	Rise Time	V <sub>DS</sub> = 6 V, V <sub>GS</sub> = 4.5 V,		1.5		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$I_{DS} = 0.5 \text{ A}, \text{ R}_{G} = 2 \Omega$		11.0		ns
t <sub>f</sub>	Fall Time			3.8		ns
DIODE C	CHARACTERISTICS		4			
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = 0.5 A, V <sub>GS</sub> = 0 V		0.73	0.9	V
Q <sub>rr</sub>	Reverse Recovery Charge			1550		рС
t <sub>rr</sub>	Reverse Recovery Time	$V_{DS}$ = 6 V, I <sub>F</sub> = 0.5 A, di/dt = 300 A/µs		6		ns

### 5.2 Thermal Information

### $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	THERMAL METRIC	TYPICAL VALUES	UNIT
Р	Junction-to-Ambient Thermal Resistance <sup>(1)</sup>	90	°C/W
R <sub>0JA</sub>	Junction-to-Ambient Thermal Resistance <sup>(2)</sup>	250	°C/VV

(1) Device mounted on FR4 material with 1 inch<sup>2</sup> (6.45 cm<sup>2</sup>), 2 oz. (0.071 mm thick) Cu.

(2) Device mounted on FR4 material with minimum Cu mounting area.



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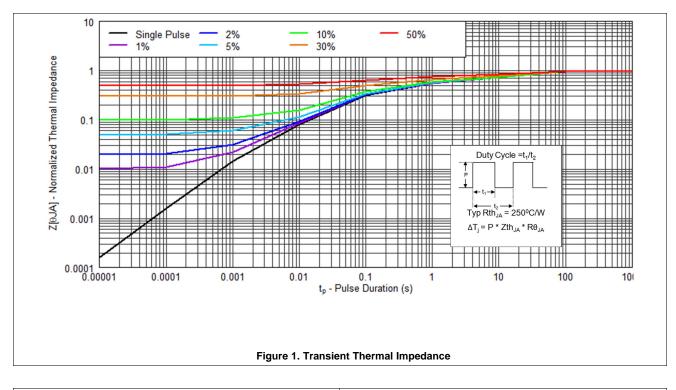
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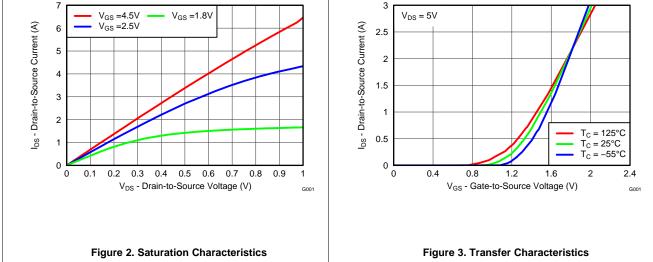
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### 5.3 Typical MOSFET Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 





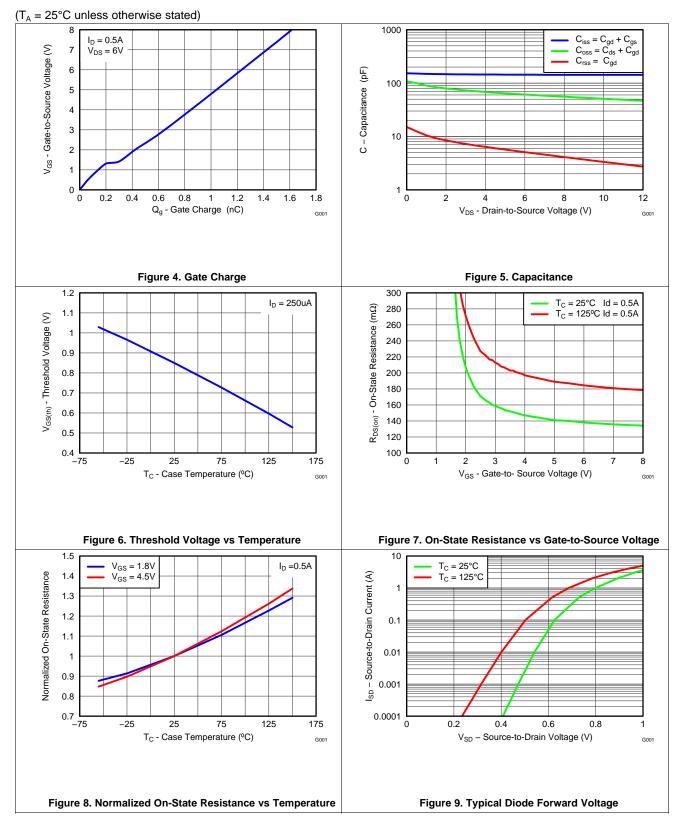


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### **Typical MOSFET Characteristics (continued)**



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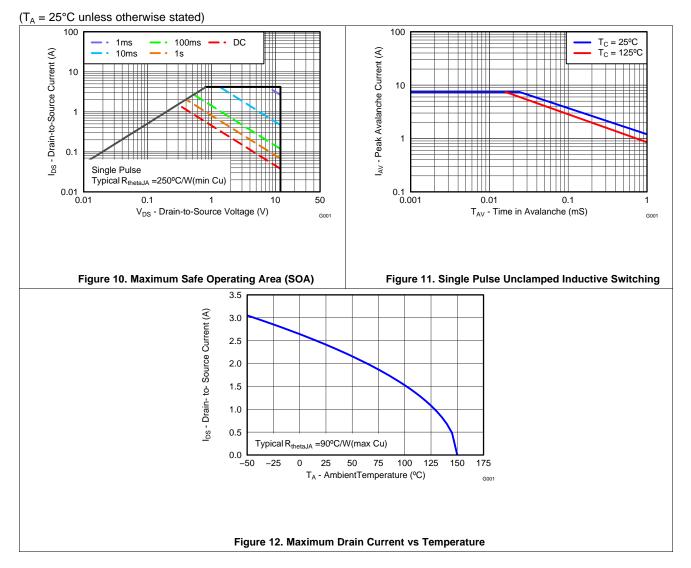
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### **Typical MOSFET Characteristics (continued)**





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### 6 Device and Documentation Support

### 6.1 Trademarks

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### 6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 6.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



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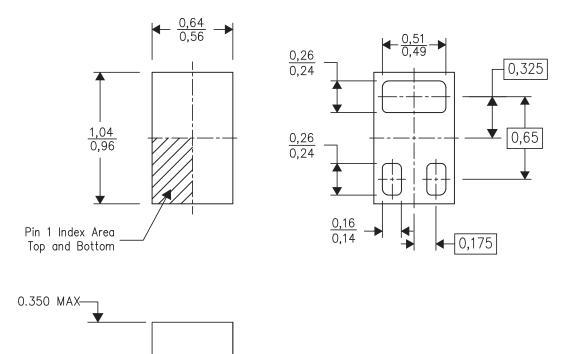


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### 7 Mechanical Data

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

### 7.1 Mechanical Dimensions



- (1) All linear dimensions are in millimeters (dimensions and tolerancing per AME T14.5M-1994).
- (2) This drawing is subject to change without notice.
- (3) This package is a PB-free solder land design.

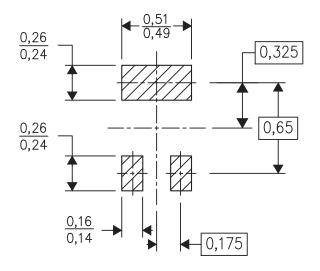


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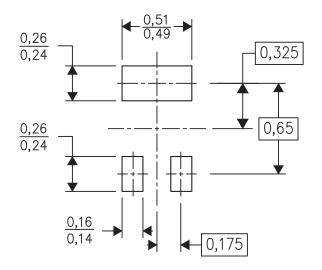
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### 7.2 Recommended Minimum PCB Layout



(1) All dimensions are in millimeters.

### 7.3 Recommended Stencil Pattern



(1) All dimensions are in millimeters.



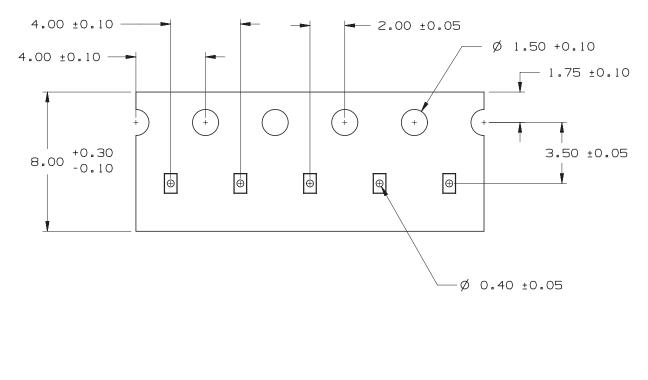
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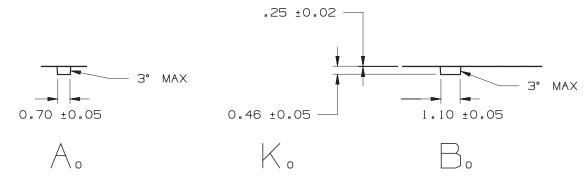
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### 7.4 CSD13381F4 Embossed Carrier Tape Dimensions





(1) Pin 1 is oriented in the top-right quadrant of the tape enclosure (quadrant 2), closest to the carrier tape sprocket holes.



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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD13381F4	ACTIVE	PICOSTAR	YJC	3	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	DQ	Samples
CSD13381F4T	ACTIVE	PICOSTAR	YJC	3	250	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	DQ	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs. LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available. OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined. Pb-Free/Green conversion plan has not been defined. Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above. Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight

in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width

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